## NSN 5962-01-310-1471



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View Online at https://aerobasegroup.com/nsn/5962-01-310-1471

Body Length:
0.840 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches

Maximum Power Dissipation Rating:
794.0 milliwatts

Operating Tempurature Range:
-55.0/+125.0 degrees celsius

Storage Tempurature Range:
-65.0/+150.0 degrees celsius

**Features Provided:** 

Hermetically sealed and burn in and schottky and monolithic

**Inclosure Material:** 

Ceramic

**Inclosure Configuration:** 

Dual-in-line

**Output Logic Form:** 

Transistor-transistor logic

**Input Circuit Pattern:** 

10 input

**Case Outline Source And Designator:** 

D-12 mil-m-38510

**Current Rating Per Characteristic:** 

140.00 milliamperes reverse current, dc absolute

**Terminal Surface Treatment:** 

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

85.00 nanoseconds delay

**Memory Device Type:** 

Prom

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

16 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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